#### 18th International Conference on RF Superconductivity

# Review of heat treatments for low beta cavities : what's so different from elliptical cavities

D. Longuevergne

SRF2017 - July 2017 - Lanzhou









## **OUTLINE**

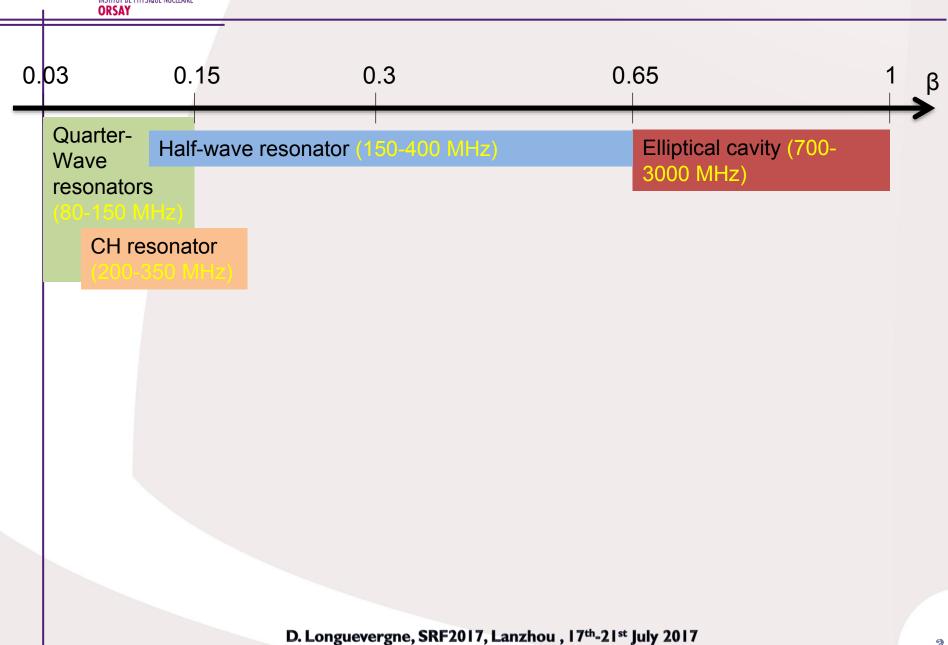
- Introduction
- Heat treatments
  - Hydrogen degassing
  - Low temperature baking
  - Perspectives on nitrogen doping... is there one ?
- Conclusion

#### SPECIAL THANKS TO:

- Z. Conway, ANL
- W.Yue, IMP
- E. Cenni, CEA
- Z.Yao, TRIUMF
- R. Laxdal, TRIUMF

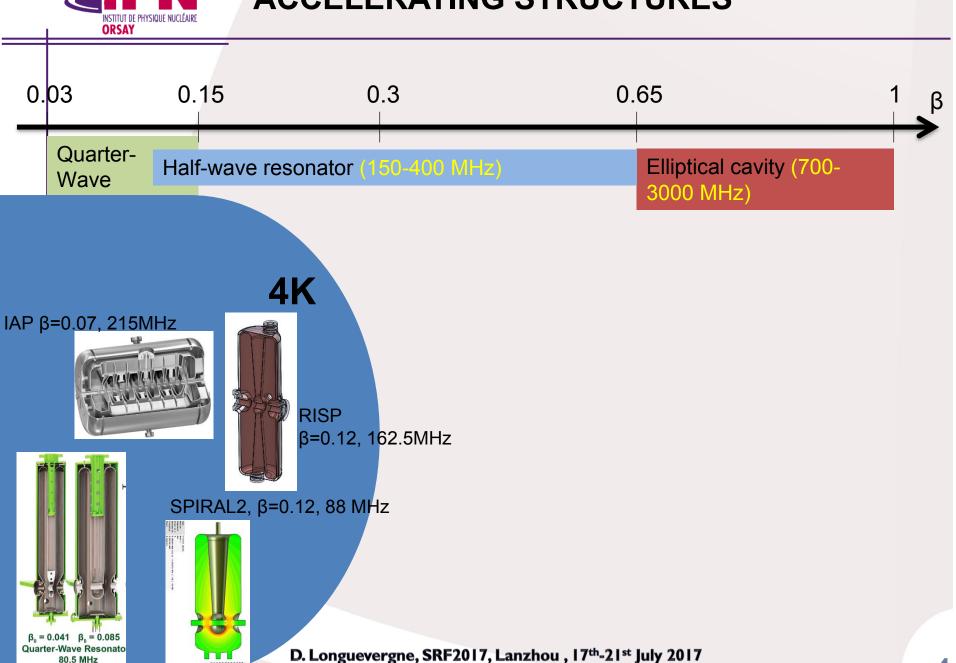


## **ACCELERATING STRUCTURES**





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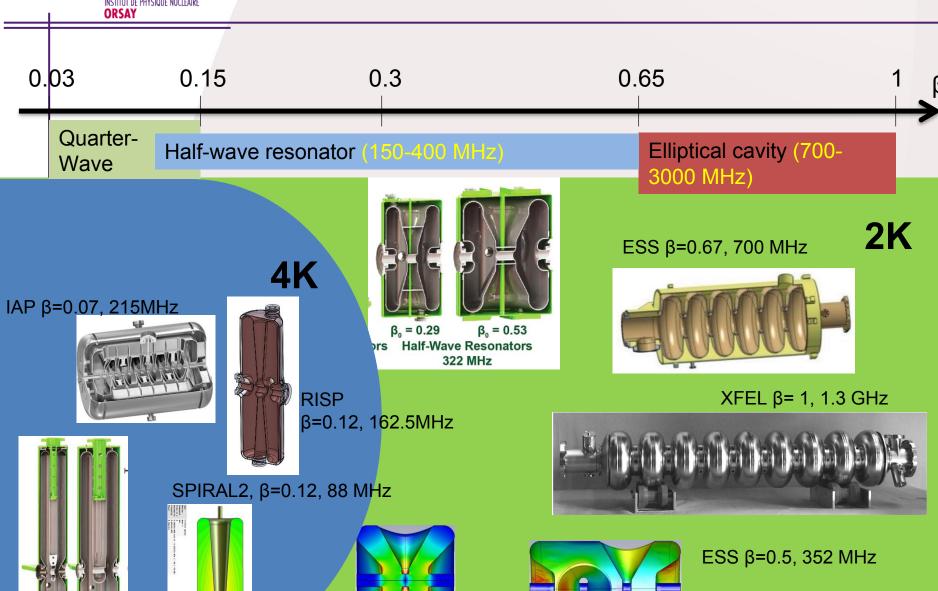


 $\beta_0 = 0.041$   $\beta_0 = 0.085$ Quarter-Wave Resonato

80.5 MHz

HIHIHIHI

#### **ACCELERATING STRUCTURES**



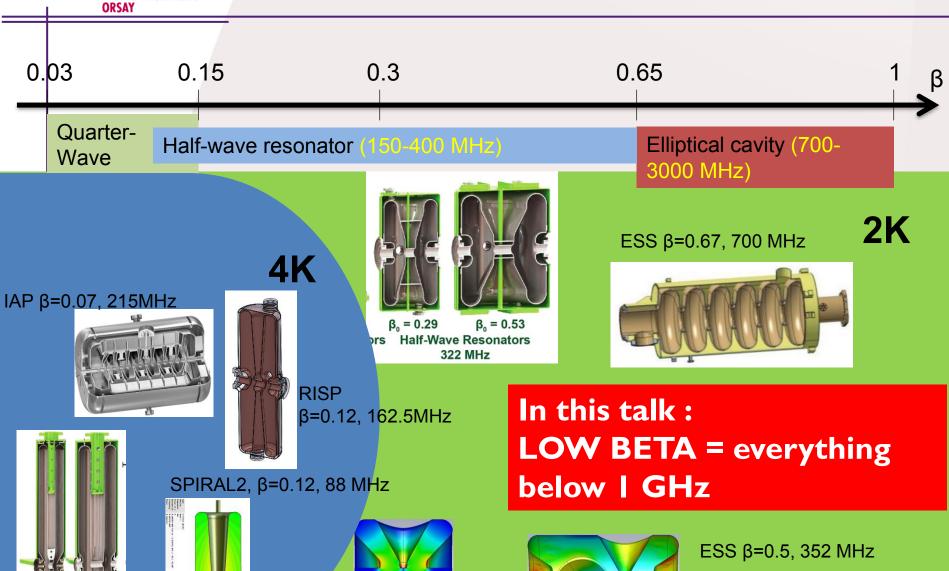
MYRRHA β=0.37, 352 MHz



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#### **ACCELERATING STRUCTURES**



MYRRHA β=0.37, 352 MHz



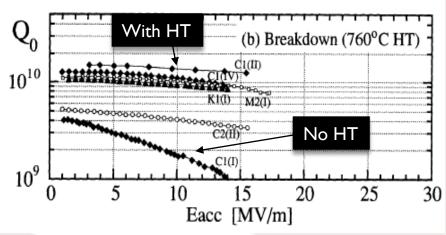
## **OUTLINE**

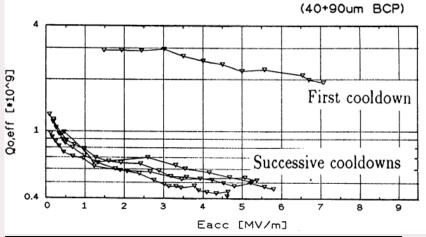
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## **HYDROGEN DEGASSING history**

- Aims at degassing hydrogen out of Niobium
  - Avoids Q-disease and irreversible degradation due to Q-disease
  - Decreases residual resistance and Q-slope
  - Releases mechanical stresses, recristalization
- But:
  - Require expensive dedicated furnace
  - Pollution of surface
    - Re-absorbtion of residual gas because oxide layer has been dissolved
    - Post chemical etching « required » to remove contaminated layer





« Q degradation of niobium cavities due to Hydrogen contamination », B. Bonin and R.W. Röth, Proceedings of the 5th SRF workshop, Hamburg, Germany, 1991



#### **HYDROGEN DEGASSING**

## ▶ 1.3 GHz elliptical cavity

- Compulsory Irreversible degradation observed.
- Done in standard preparation
- Done with bare cavity
- Typically at 800°C during 2-3h.

Temperature limitation to limit recristalization and softening

#### Low beta resonators

FRIB, C-ADS, IFMIF).

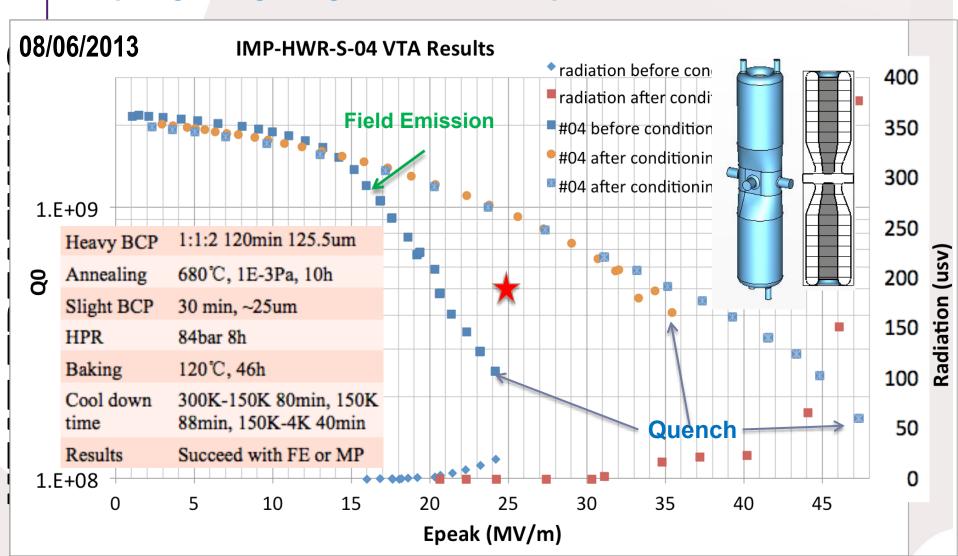
- Not compulsory for QWR up to 170 MHz. Accelerators with non degassed cavities (ISAC2, ALPI, Saraf, Spiral2). Accelerators with degassed cavities (ATLAS,
- Looks compulsory for Spoke resonators at 352 MHz.

  Irreversible degradation observed in VT
- Done with/without dressed cavity
- Typically at 600°C 650°C during 10h.

  Temperature limitation due to brazed stainless steel parts



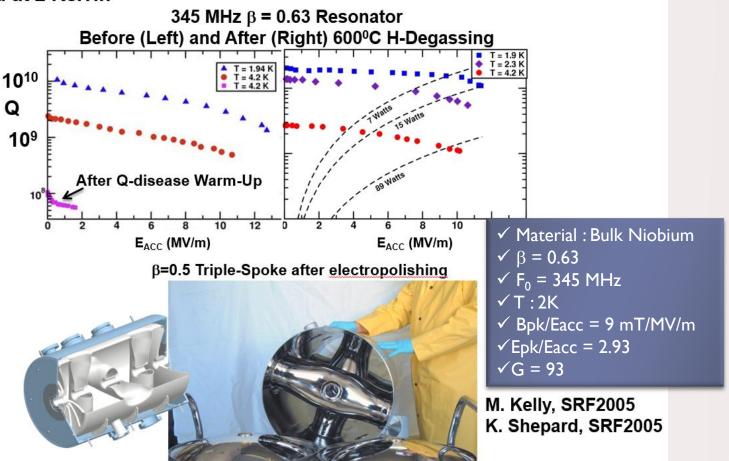
Hydrogen degassing at IMP: Courtesy of W.Yue





Hydrogen degassing at ANL : Courtesy of Z. Conway

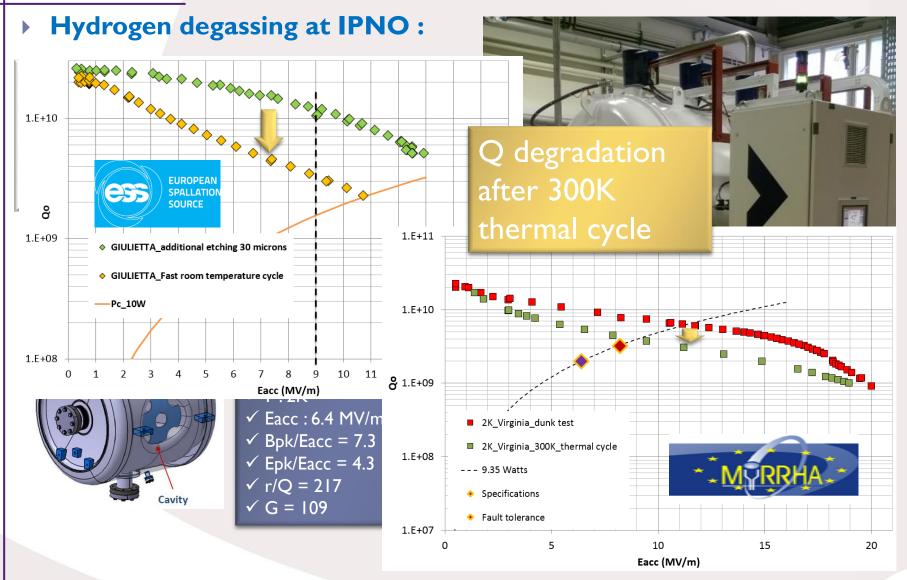
Results for 345 MHz Beta = 0.63 Triple Spoke Resonator After Hydrogen Degassing, Performance Indicated that Cavities Should be Operated at 2 Kelvin



Argonne 📤





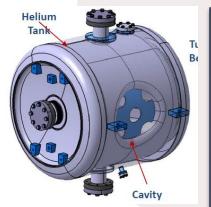




#### Hydrogen degassing at IPNO:



- ✓ Material : Bulk Niobium
- $\checkmark \beta = 0.5$
- $✓ F_0 = 352 \text{ MHz}$
- ✓ T:2K
- ✓ Eacc : 9 MV/m
- ✓ Bpk/Eacc = 6.9 mT/MV/m
- $\checkmark$  Epk/Eacc = 4.3
- $\sqrt{r/Q} = 426$
- ✓ G = 130



- ✓ Material : Bulk Niobium
- ✓  $\beta = 0.37$
- $✓ F_0 = 352 \text{ MHz}$
- ✓ T:2K
- ✓ Eacc : 6.4 MV/m
- ✓ Bpk/Eacc = 7.3 mT/MV/m
- $\checkmark$  Epk/Eacc = 4.3
- $\sqrt{r/Q} = 217$
- $\sqrt{G} = 109$

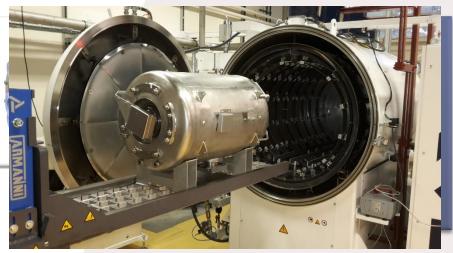




Furnace commissioned in 2016



#### Hydrogen degassing at IPNO:



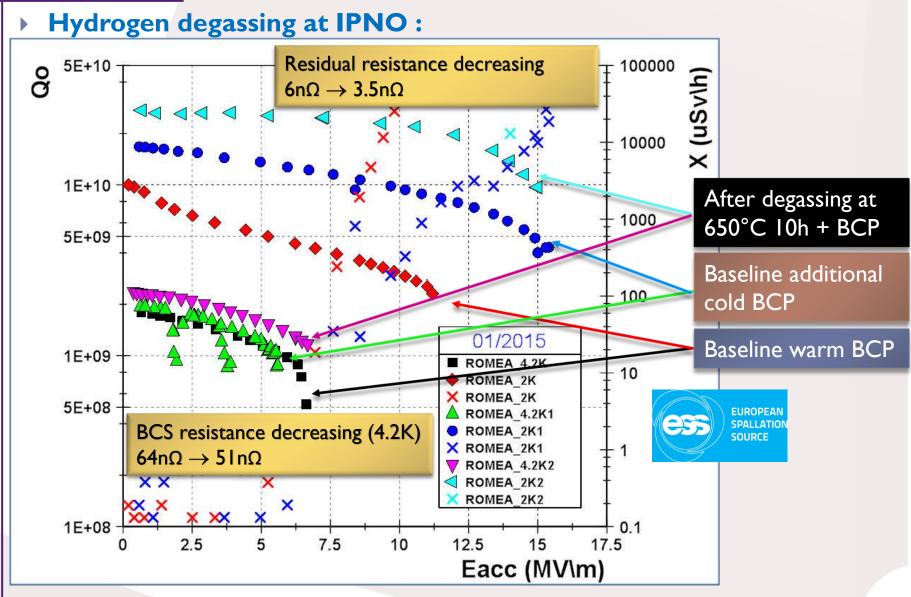




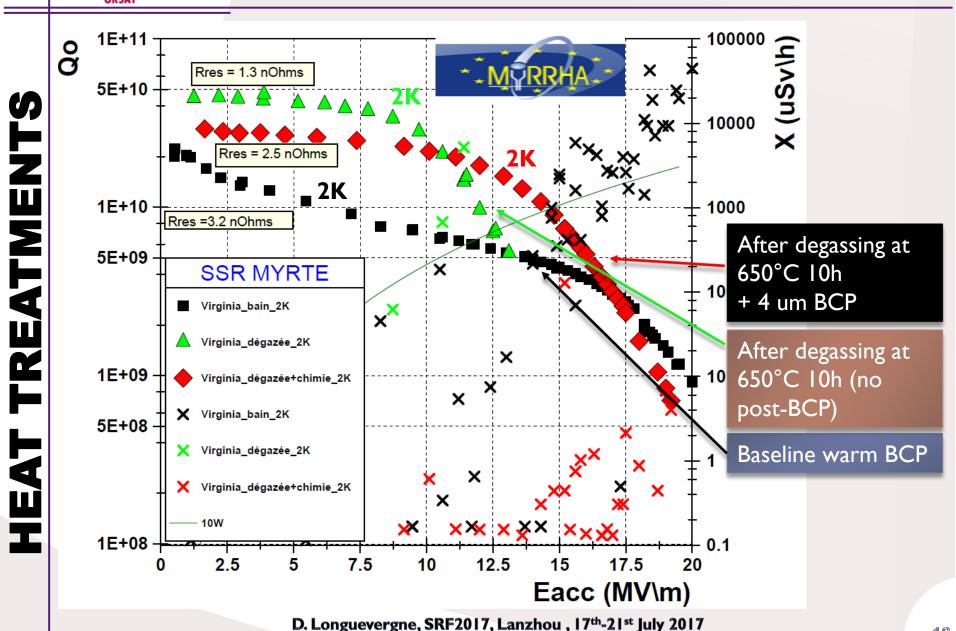
Furnace commissioned in 2016





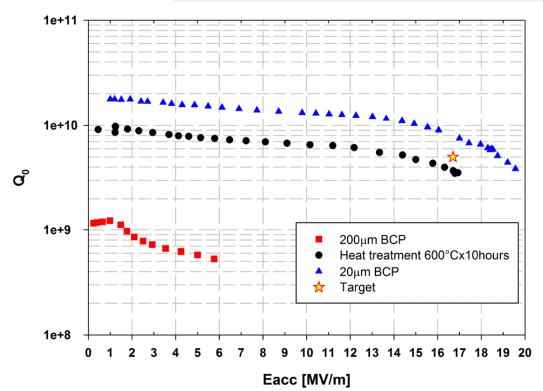


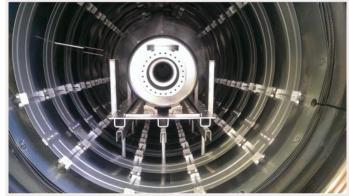


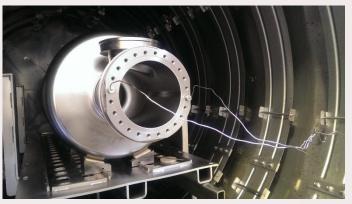














- ✓ Material : Bulk Niobium
- ✓  $\beta = 0.67$
- $✓ F_0 = 704 \text{ MHz}$
- ✓ T:2K
- $\checkmark$  Bpk/Eacc = 4.8 mT/MV/m
- $\checkmark$ Epk/Eacc = 3.8
- √G = 197

Treated at Zanon facility

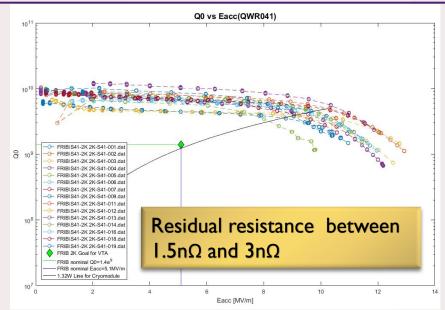
COURTESY OF E. CENNI, CEA

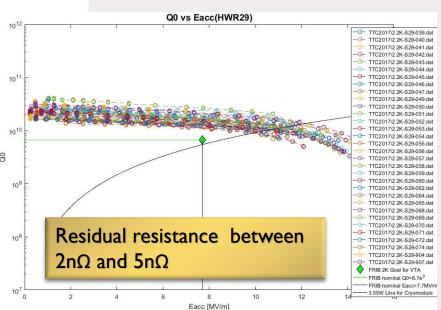


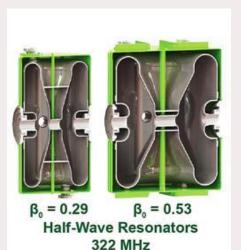


- FRIB example after degassing
- Unfortunately no data before hydrogen degassing for comparison









K. Saito, February 2017 TTC201702

D. Longuevergne, SRF2017, Lanzhou, 17th-21st July 2017

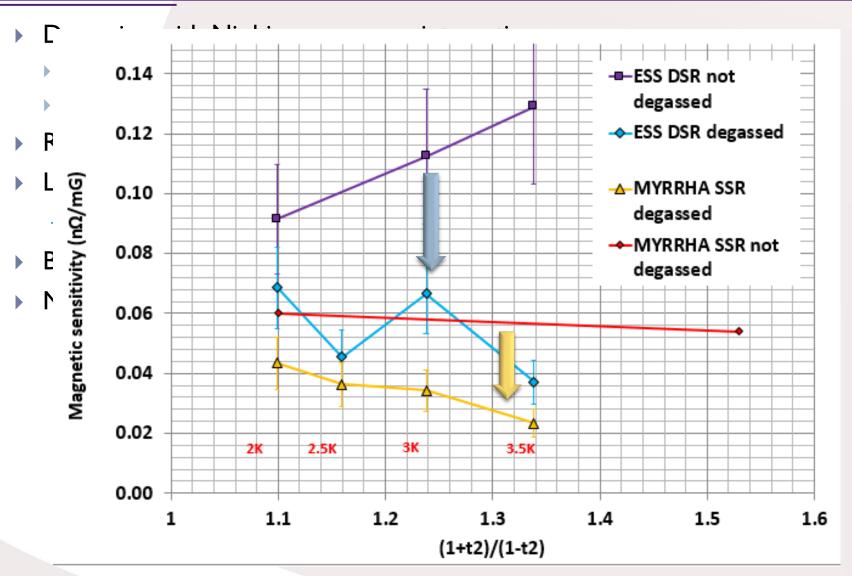


- Degassing with Niobium caps very interesting
  - No post etching required
  - Allow alternative treatment like N2 infusion
- ▶ Residual resistance is decreased → No hydrogen precipitation
- Linear dependence of Q-slope is eliminated
  - → Disparition of Josephson weak links [\*]
- ▶ BCS resistance is decreased as well  $\rightarrow$  « doping of Niobium », RRR  $\downarrow$
- Magnetic sensitivity is decreased
  - → Observed on elliptical cavities
  - → And also on Spoke cavities at 352 MHz

$$R_{BCS} = \frac{A \cdot \omega^2}{T} \cdot \exp\left(\frac{-\Delta}{k_B \cdot T}\right)$$









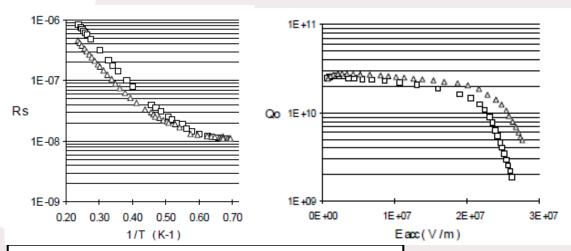
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## Low temperature baking for elliptical cavities

- Most of labs converged toward 120°C during 48h
- Aims at removing the high field Q-slope
  - First reported by B. Visentin in 1998.
  - Decreases BCS resistance
  - Decreases (for BCP cavity) or eliminates (for EP cavity) the high field Q-slope
  - Could be used to accelerate drying of cavity
- But:
  - Increases residual resistance



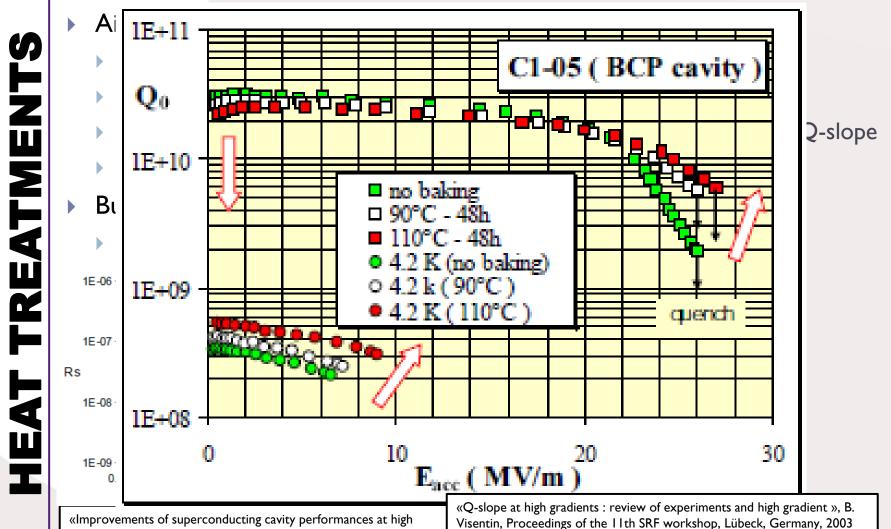
«Improvements of superconducting cavity performances at high accelerating gradients », B. Visentin et al., Proc EPAC 1998, p. 1885



## Low temperature baking for elliptical cavities

Most of labs converged toward 120°C during 48h

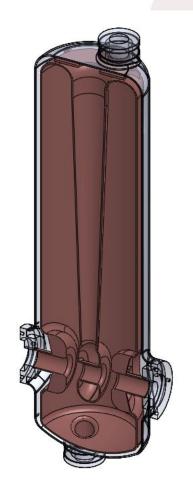
accelerating gradients », B. Visentin et al., Proc EPAC 1998, p. 1885

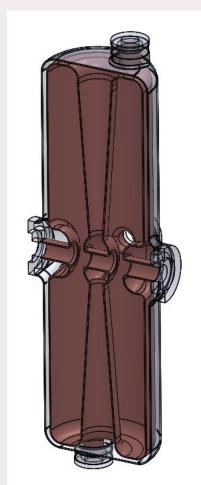






#### Baking for RISP:





- 81.25MHz QWR and 162.5MHz HWR designed by RISP.
- Cavity treatments
  - 120μm BCP (+15μm for HWR)
  - HPR
  - 48hr 120°C bake
- Cavities were tested before and after bake.

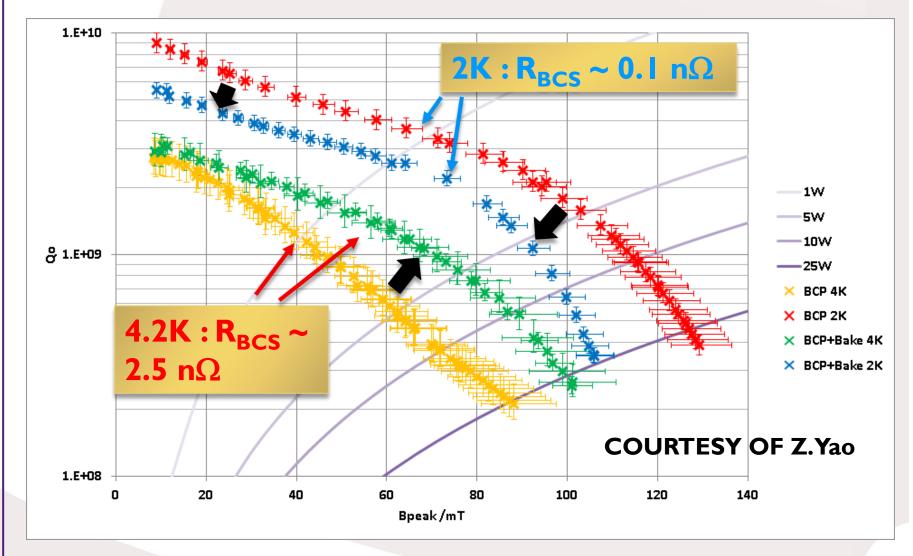
	QWR	HWR	Unit
Frequenc y	81.25	162.5	MHz
β	0.047	0.12	1
$\mathbf{L}_{\mathrm{eff}}$ = $\beta\lambda$	0.173	0.221	m
$\mathbf{E}_{\mathrm{peak}}/\mathbf{E}_{\mathrm{acc}}$	5.3	5.6	1
B <sub>peak</sub> /E <sub>acc</sub>	9.5	8.2	mT/MV/ m
G	21	40	Ω
U/E <sub>acc</sub> <sup>2</sup>	0.126	0.159	J/(MV/m)

COURTESY OF Z. Yao





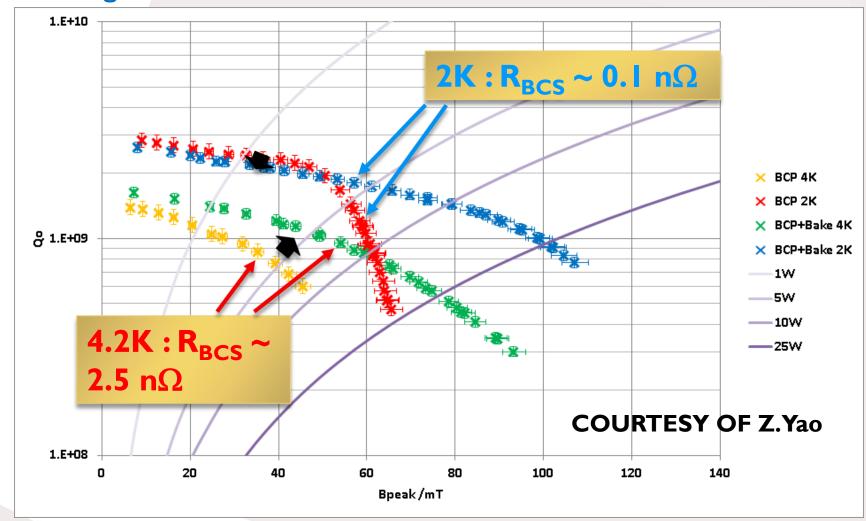
#### ▶ Baking for RISP : 81 MHz QWR







#### Baking for RISP: 162 MHz HWR

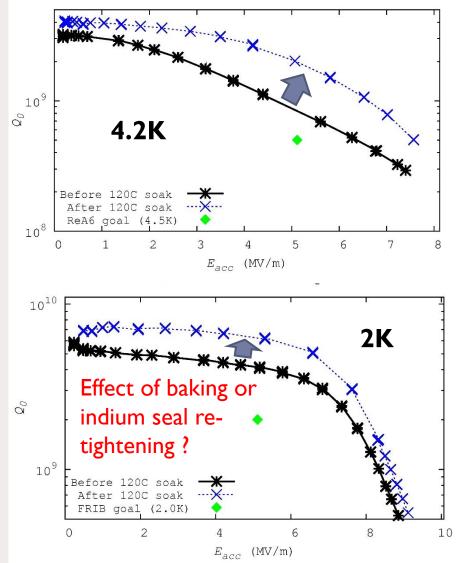






Baking at 120°C during 48h at FRIB: 80.5 MHz QWR





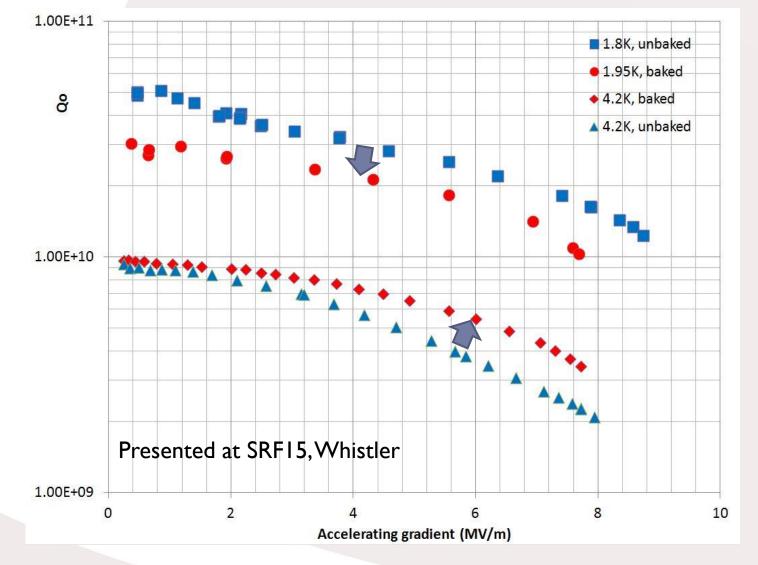
Presented at TTC meeting by J. Popielarski, december 2011 D. Longuevergne, SRF201

D. Longuevergne, SRF2017, Lanzhou, 17th-21st July 2017





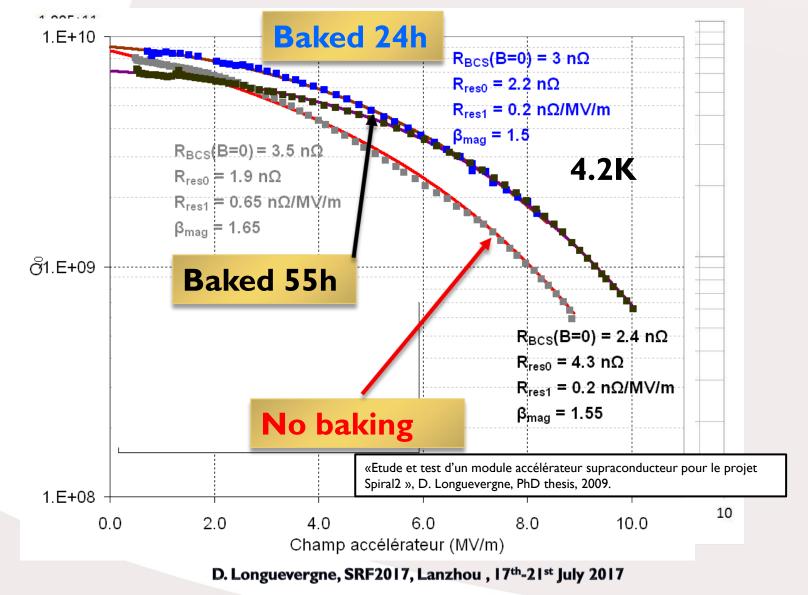
#### ▶ Baking at I20°C at IPNO:88 MHz QWR













- ▶ Residual resistance is increased → diffusion of surface impurities
- ▶ BCS resistance is decreased → reduction of electron mean free path
- ▶ 4.2 K Q-slope is decreased → origin of Q-slope is BCS
- Difference between elliptical and low beta :
  - For elliptical cavities: baking affects only the high field Q-slope (>20 MV/m)
  - For low beta cavities: Q-slope impacted at low field

Cavity	Frequency	Pre-treatment	Residual resistance	BCS resistance
QWR RISP	81.25 MHz	ВСР	<b>↑</b>	<b>\</b>
HWR RISP	162.5 MHz	ВСР	<b>↑</b>	<b>\</b>
QWR ReA3	80.5 MHz	BCP + 600°C degassing	<b>↓??</b>	<b>\</b>
QWR Spiral2	88 MHz	ВСР	<b>↑</b>	<b>\</b>



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## N<sub>2</sub> « doping » for elliptical cavities

- Nitrogen doping reported in 2013 at fermilab
  - Cavity exposed to nitrogen gas at the end of thermal cycle at 800° C
  - Small chemical etching required to remove over-doped layer
- Positive effects :
  - Decrease of BCS resistance
  - **BCS** resistance is improving with accelerating gradient (anti Q-slope)
- Negative effects :
  - Quenching gradient is reduced
  - Magnetic sensitivity is drastically increased
- Heat treatment (300° C to 800° C) with N<sub>2</sub>/Ar refill already tried by B. Visentin in 2001
  - Anomalously low BCS resistance observed. No mention of anti Q-slope
- ▶ G. Ciovatti reported nitridization treatment at 400° C following a 800° C treatment in 2010
  - Improvement of residual resistance

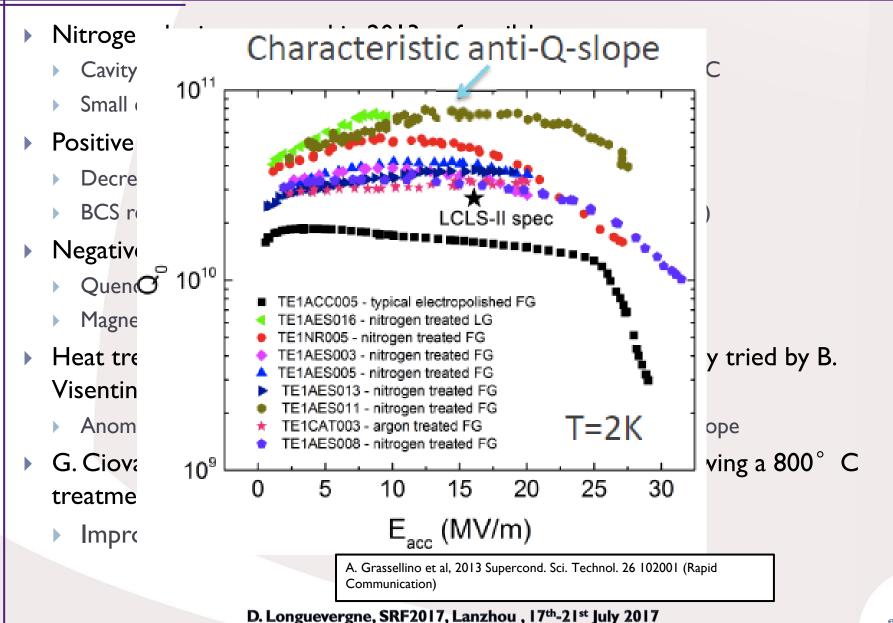


nitrogen doping

**5**0

**Perspectives** 

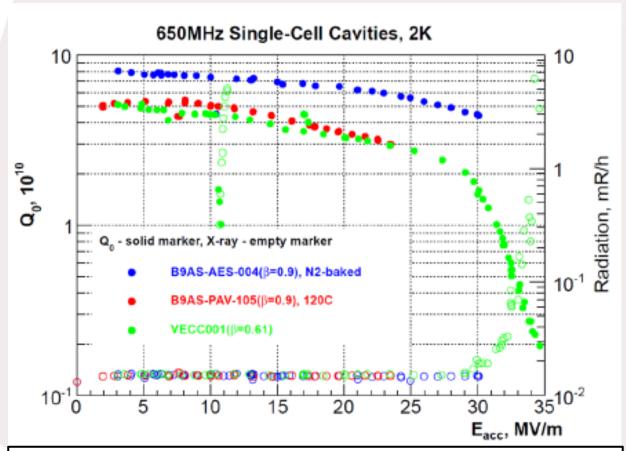
## N<sub>2</sub> « doping » for elliptical cavities





## N<sub>2</sub> « doping » for low beta

Only one example at 650 MHz



CAVITY PROCESSING AND PREPARATION OF 650 MHz ELLIPTICAL CELL CAVITIES FOR PIP-II\*, A. M. Rowe et al., Proceedings of LINAC2016, East Lansing, US.





## N<sub>2</sub> « doping » for low beta

- Nitrogen doping keeps residual resistance low and decreases BCS resistance
- To be beneficial residual resistance has to be low compaired to BCS resistance
- What does that mean for low beta cavities :
  - If operated at 2K
    - No point to dope up to 500 MHz, as BCS resistance is low and MFQS is negligeable
  - If operated at 4.2K
    - Worth doing it especially if Q-slope is from BCS and not residual resistance
- Could nitrogen doping allow 4.2K operation of Spoke cavities at 352 MHz?

$R_{BCS}$ (n $\Omega$ )	4.2K	2K	1.8K	I.5K
1300 MHz	585	15	6.5	1.2
700 MHz	174	4.3	1.9	0.35
352 MHz	44	- 1	0.5	0.09
176 MHz		0.3	0.1	0.02
88 MHz	3	0.07	0.03	0.006

D. Longuevergne, SRF20



## **CONCLUSION**

	I.3 GHz Elliptical	Observed improvements	Low beta cavities
Hydrogen degassing	<ul> <li>Compulsory</li> <li>Done without tank</li> <li>Done at 800°C</li> <li>Done during 3h</li> </ul>	<ul> <li>Improvement of Residual</li> <li>Improvement of BCS</li> <li>Improvement of Q-slope</li> <li>Q-disease disappears</li> </ul>	<ul> <li>Not compulsory below 300 MHz</li> <li>Done with/without tank</li> <li>Brazed parts → done at 600°C</li> <li>Done during 10h</li> </ul>
120°C baking	<ul><li>Done during 48h</li><li>Hot air/nitrogen blown around cavity</li></ul>	<ul> <li>Improvement of BCS</li> <li>Degradation of Residual</li> <li>Improves         <ul> <li>Improves</li></ul></li></ul>	<ul> <li>Done during 48h</li> <li>Hot air blown in helium tank</li> <li>Heating wires</li> </ul>
Nitrogen doping		<ul> <li>Improvement of BCS resistance</li> <li>Residual resistance stays constant</li> </ul>	<ul> <li>Tried on 650 MHz only</li> <li>Will be tried on Spoke at 352 MHz</li> </ul>
		- Anti Q No anti slope Q-slope	



# THANKS A LOT FOR YOUR ATTENTION

### AND MANY THANKS FOR PROVIDING MATERIAL TO:

- Zack Conway, ANL
- Zhongyuan Yao, TRIUMF/RISP
- Yue Weiming, IMP
- Enrico Cenni, CEA



## THE BCS RESISTANCE

$$R_{BCS} = \frac{8 \cdot 10^{-5}}{T} \cdot f^2 \cdot \exp\left(-\frac{1.83 \cdot Tc}{T}\right)$$

$R_{BCS}$ (n $\Omega$ )	4.2K	2K	1.8K	I.5K
1300 MHz	585	15	6.5	1.2
700 MHz	174	4.3	1.9	0.35
352 MHz	44	ı	0.5	0.09
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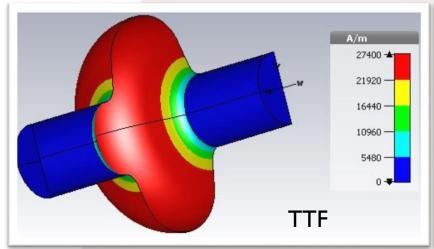
Cavity	Frequency	Residual (nΩ)		$f A$ (10 <sup>-5</sup> n $\Omega$ K/s <sup>-2</sup> )	
		Before HT	After HT	Before HT	After HT
QWR FRIB	80.5 MHz	X	1.5	X	7
Spoke ANL	345 MHz	6.5	4.5	7	6
Spoke IPNO	352 MHz	3.2	I.3 (no BCP)	9.5	8
Elliptical ESS	704 MHz	150	6	15	12.5
Elliptical KEK [**]	I.3 GHz	60	10	X	X

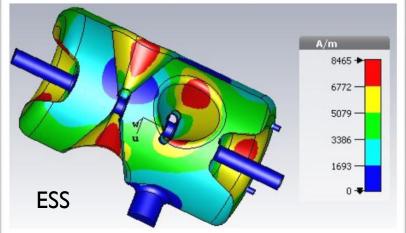
[\*]: « Additional losses in high purity niobium cavities related to slow cooldown and hydrogen segregation », J. Halbritter et al., Proceedings of the 6th SRF workshop, Newport News, USA, 1993

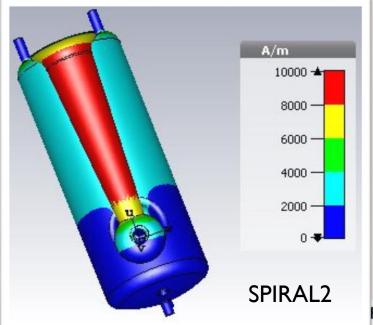


# FIELD DISTRIBUTION

Field distribution very different depending on the geometry







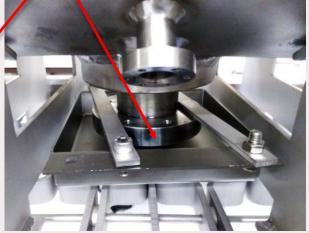






Niobium samples have been installed in cavity





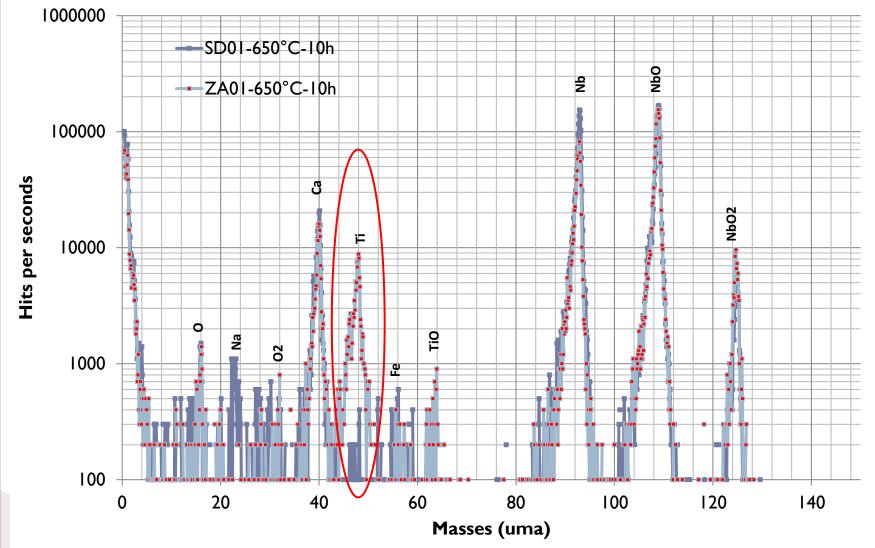


- SIMS (Secondary Ion Mass Spectrometer) analysis to know what is on the surface after heat treatment
  - Compact SIMS from Hiden Analytical





A cavity not shielded during heat treatment:

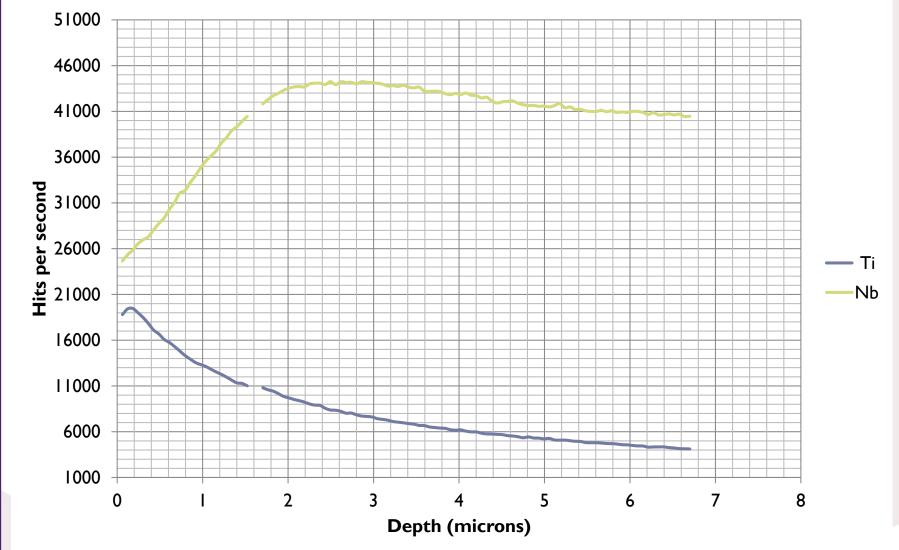








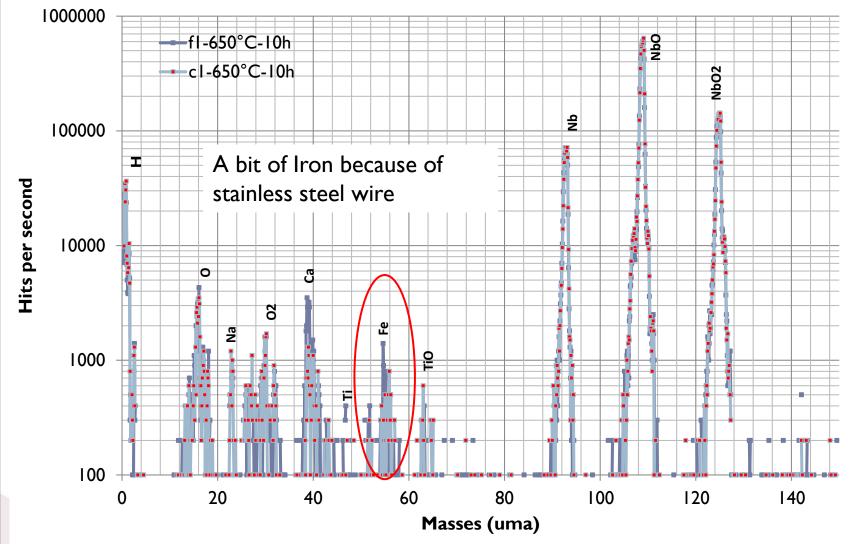
# A cavity not shielded during heat treatment:







A cavity shielded during heat treatment:

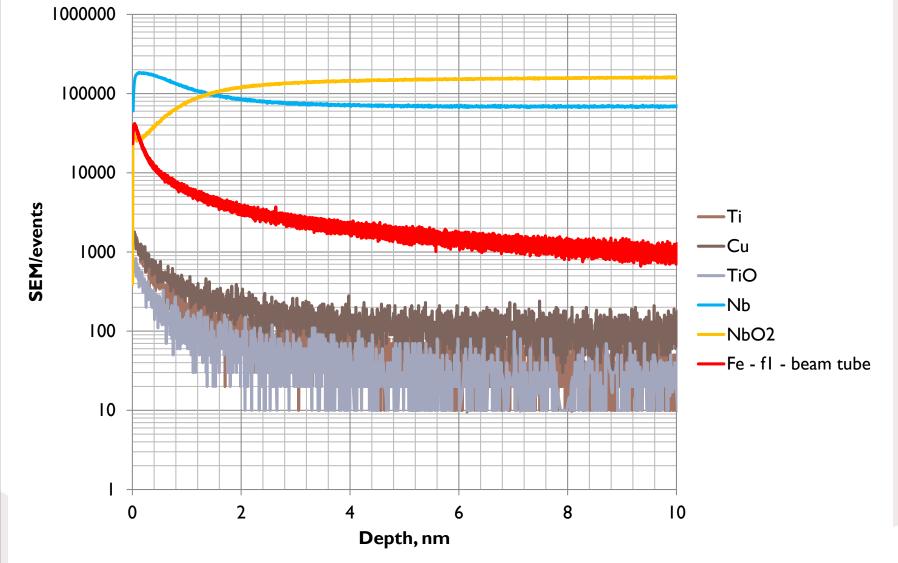








A cavity shielded during heat treatment :





# How to compare elliptical and low beta

•	eters
	rame

Cavity type	β	T° (K)	<b>G</b> (Ω)	Qo at I nΩ res	F (MHz)	Eacc (MV/m)	Bpk/Eacc (mT/MV/m)
QWR (FRIB)	0.041	2	15	1.4 <sup>E</sup> 10	80.5	5.3 (54.6)	10.3
QWR (SPIRAL2)	0.12	4.2	33	8.2 <sup>E</sup> 9	88	6.5 (61.7)	9.5
HWR (RISP)	0.12	2	40	3.2 <sup>E</sup> 10	162	5.9 (48.4)	8.2
HWR (FRIB)	0.53	2	107	5.3 <sup>E</sup> 10	322	7.5 (63)	8.4
SPOKE (ESS)	0.5	2	133	6 <sup>E</sup> 10	352	9 (63)	7
Elliptical (ESS)	0.67	2	197	3.4 <sup>E</sup> 10	704	16.7 (83.5)	4.8
Elliptical (XFEL)	I	2	271	1.5 <sup>E</sup> 10	1300	23.6 (99)	4.2

D. Longuevergne, SRF2017, Lanzhou, 17th-21st July 2017



# At CERN

# At FERMILAB

